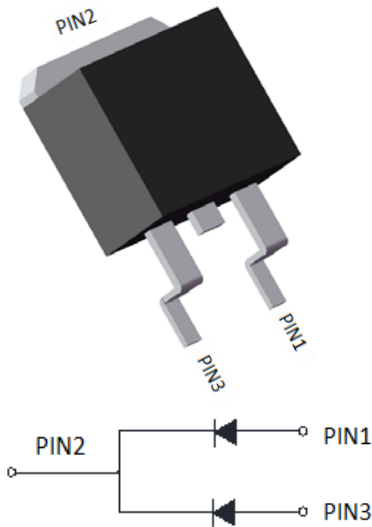


Ultra-Fast Recovery Diodes 15A*2 FRED Pt



Features

- Adopt FRED chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-263
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings (T_j=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MURB3060CT
Device marking code			MURB3060CT
Repetitive Peak Reverse Voltage	V _{RRM}	V	600
Average Rectified Output Current @60Hz sine wave, R-load, T _c (FIG.1)	I _O	A	30
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _j =25°C	I _{FSM}	A	150
Current Squared Time @1ms≤t≤8.3ms T _j =25°C,	I ² t	A ² s	93
Storage Temperature	T _{stg}	°C	-55 ~ +175
Junction Temperature	T _j	°C	-55 ~ +175
Junction capacitance @4V,1MHz	C _j	pF	98



MURB3060CT

■Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max
Instantaneous forward voltage drop per diode	V_{FM}	V	$I_{FM}=15.0A$ @ $T_J=25^{\circ}C$	-	1.45	1.60
			$I_{FM}=15.0A$ @ $T_J=150^{\circ}C$		1.25	1.40
DC reverse current at rated DC blocking voltage per diode	I_{RRM1}	uA	$V_{RM}=V_{RRM}$ $T_J=25^{\circ}C$	-	-	5
	I_{RRM2}		$V_{RM}=V_{RRM}$ $T_J=150^{\circ}C$	-	-	200
Reverse Recovery Time	T_{rr}	ns	$I_F=0.5A$ $I_{RM}=1A$ $I_{RR}=0.25A$ $T_J=25^{\circ}C$	-	26	35-
			$T_J=25^{\circ}C$	-	115	-
			$T_J=125^{\circ}C$	-	200	-
Peak recovery current	I_{RRM}	A	$T_J=25^{\circ}C$	-	5.0	-
			$T_J=125^{\circ}C$	-	10.5	-
Reverse recovery charge	Q_{rr}	nC	$T_J=25^{\circ}C$	-	285	-
			$T_J=125^{\circ}C$	-	1000	-

■Thermal Characteristics ($T_J=25^{\circ}C$ Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MURB3060CT
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	$^{\circ}C/W$	2.0
	Between junction and Air	$R_{\theta J-A}$	$^{\circ}C/W$	50

■Characteristics (Typical)

FIG1: I_o - T_c Curve

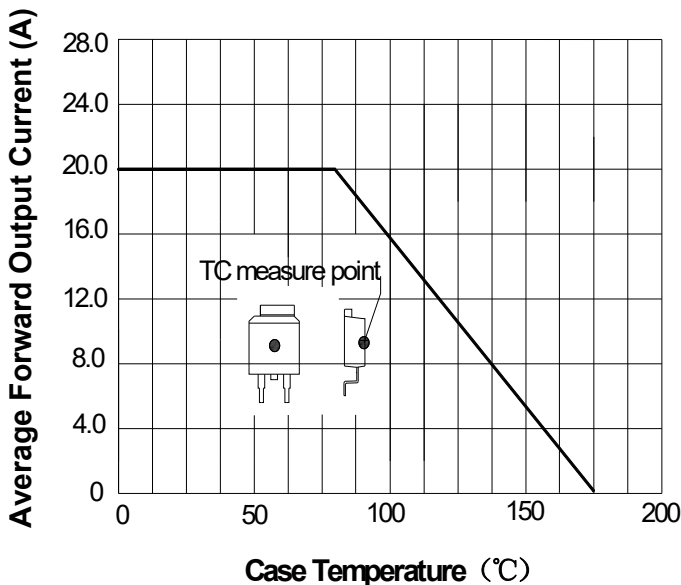


FIG2: Surge Forward Current Capability

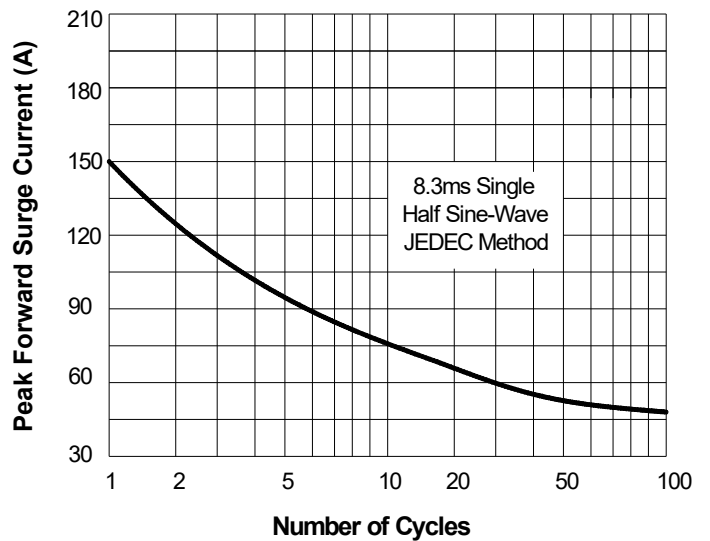


FIG3: Forward Voltage

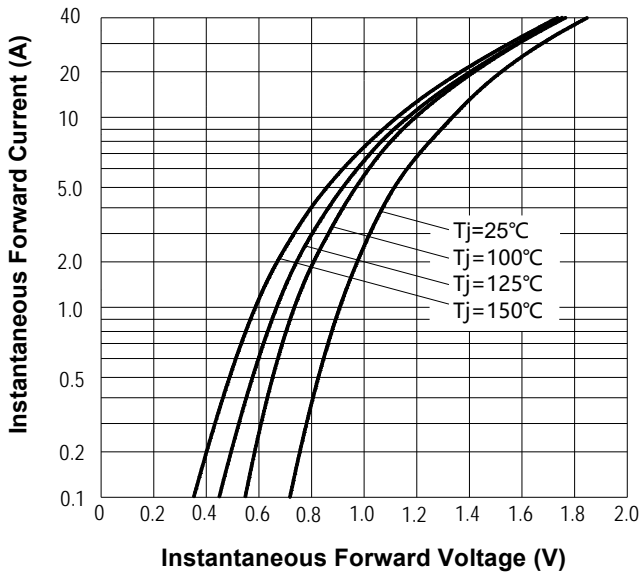


FIG.4: Instantaneous Reverse Characteristics

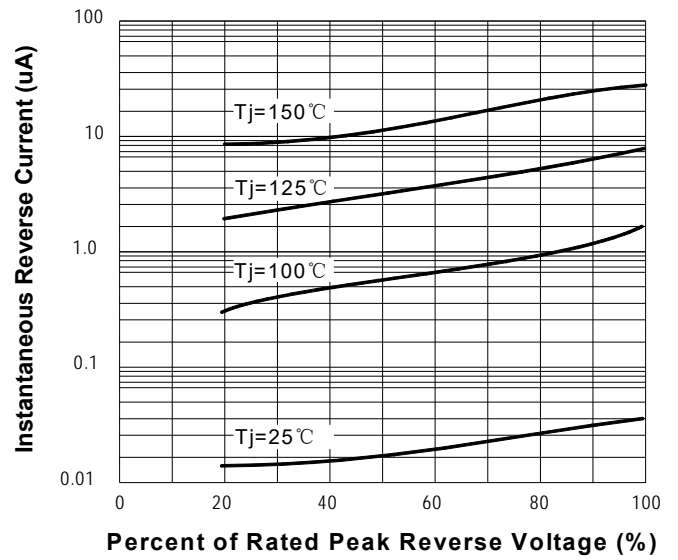
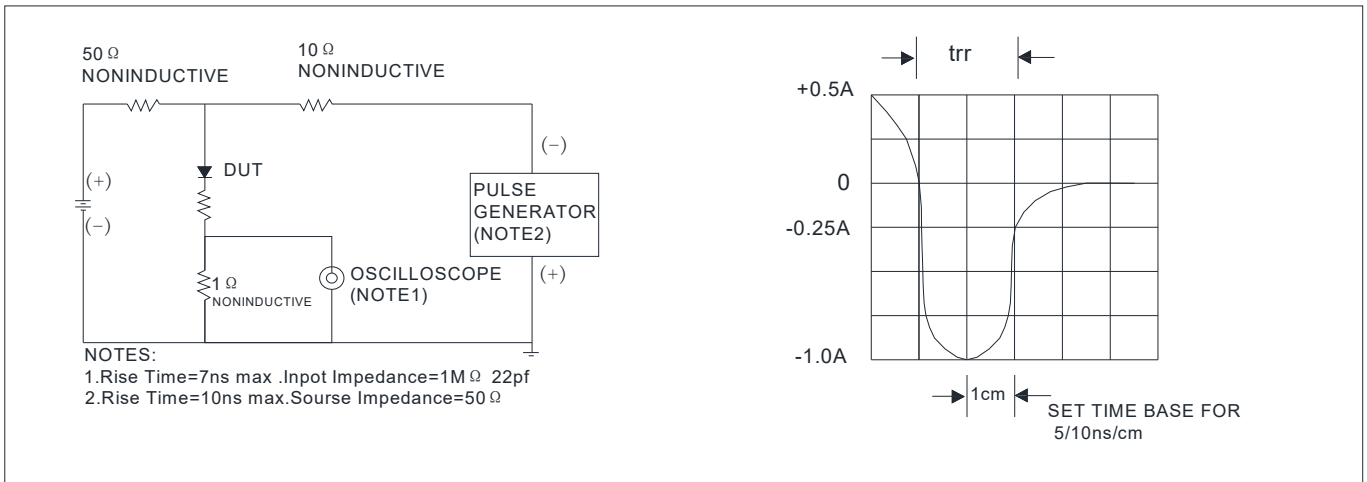


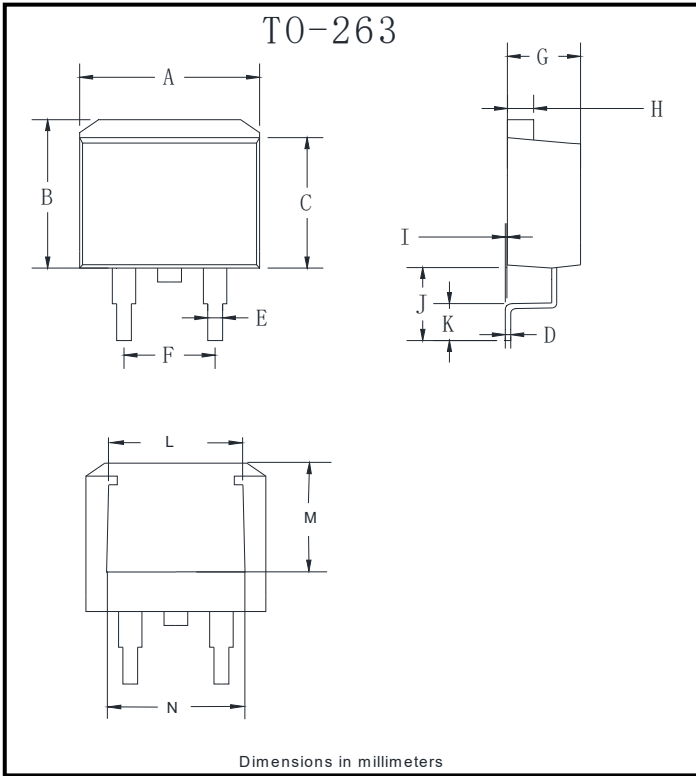
FIG.5: Diagram of circuit and Testing wave form of reverse recovery time





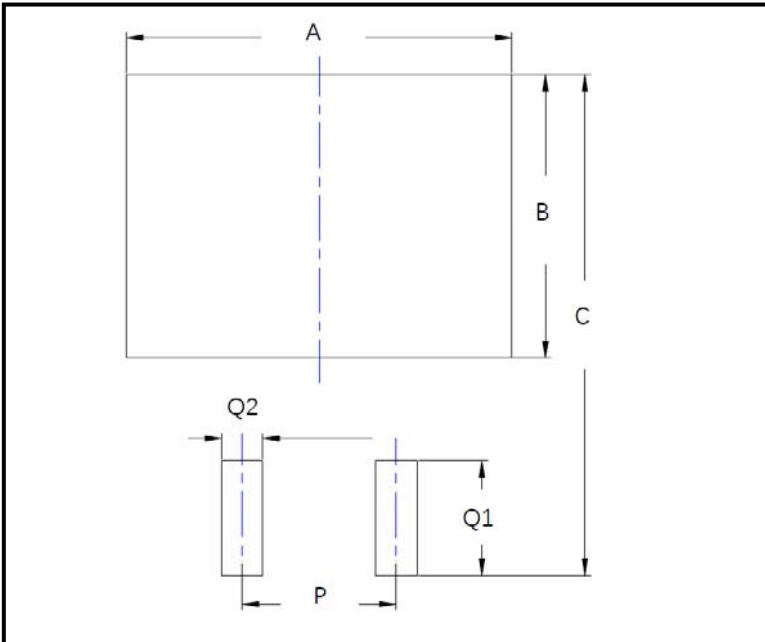
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■ Outline Dimensions



TO-263		
Dim	Min	Max
A	9.5	11.5
B	9.7	10.5
C	8.4	9.0
D	0.28	0.64
E	0.68	0.94
F	4.55	5.6
G	4.04	5.10
H	1.14	1.4
I	0	0.2
J	4.9	6.05
K	1.79	2.79
L	7.3	7.9
M	6.2	6.8
N	7.6	8.2

■ Suggested Pad Layout



Dim	Millimeters
A	12.7
B	9.4
C	16.6
P	5.08
Q1	3.8
Q2	1.35



MURB3060CT

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The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Yangjie or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

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